

ERNST-MORITZ-ARNDT UNIVERSITY OF
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MASTER THESIS

Kinetic effects in RF discharges

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“Without encroaching upon grounds appertaining to the theologian and the philosopher, the domain of natural sciences is surely broad enough to satisfy the wildest ambition of its devotees. [. . .] The work may be hard, and the discipline severe; but the interest never fails, and great is the privilege of achievement. ”

— John William Strutt, 3rd Baron Rayleigh, 1884
in: Address to the British Association in Montreal

Declaration of Authorship

I hereby certify that this thesis has been composed by me and is based on my own work, unless stated otherwise. No other person's work has been used without due acknowledgement in this thesis. All references and verbatim extracts have been quoted, and iall sources of information, including graphs and data sets, have been specifically acknowledged.

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Signature of author
Greifswald; August 17, 2017

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List of Abbreviations

abbreviation	full expression
e.g.	exempli gratia; <i>for example</i>
etc.	et cetera; <i>and so on</i>
ac	alternating current
dc	direct current
rf, RF	radio frequency
ccrf	capacitively coupled radio frequency
EDF	energy distribution function
EDV	<i>german: Energieverteilungsfunktion</i> , energy distribution function
EEDF	electron energy distribution function
IEDF	ion energy distribution function
p., pp.	page, plural pages
ff.	folio; <i>on the (next) page</i> , ablative of folium (<i>page</i>)
HWA	hard wall approximation
MS	mass spectrometer
PROES	phase resolved emission spectroscopy
MWI	microwave interferometer
AN	antenna
FC	flow controller
PIC	particle-in-cell
MCC	Monte-Carlo-Colissions

Table 1: List of abbreviations and their corresponding phrases. If specified, the translation or an equivalent expression is written.

Physical Quantities

Quantity	Unit	Symbol	Dimension	Value
Speed of Light	m/s	c_0	L^1T^{-1}	$2,997 \cdot 10^8$
thermal velocity	m/s	$v_{th,j}$	L^1T^{-1}	
drift velocity	m/s	$v_{D,j}, u_j$	L^1T^{-1}	
Boltzmann constant	eV/K	k_B	$M^1L^2T^{-2}K^{-1}$	$8,617 \cdot 10^{-23}$
mobility	cm^2/Vs	μ_j	$I^1T^2M^{-1}$	
planck constant	eVs	\hbar	$G^{-1/2}c^{6/2}\varepsilon_0^{1/2}$	$4,1345 \cdot 10^{-15} \text{ eVs}$ $6,646 \cdot 10^{-34} \text{ Js}$
kinetic temperature	eV	T_j	$M^1L^2T^{-2}$	$1 \text{ eV} = 1,902 \cdot 10^{-19} \text{ K}$
elementary charge	C	e	I^1T^1	$1,902 \cdot 10^{-19}$
electric charge	C	Q, q	I^1T^1	
particle mass	kg	m_j	M^1	electron: $9,109 \cdot 10^{-31}$ ion: $5,310 \cdot 10^{-26}$ anion: $5,143 \cdot 10^{-26}$
reduced mass	kg	$\mu_{j,k}$	M^1	
distance,location	cm	r, \vec{r}	L^1	
Debye length	cm	$\lambda_{D,j}$	L^1	
particle distance	cm	\bar{b}	L^1	
mean free path	cm	$s_{mfp,j}$	L^1	
particle density	cm^{-3}	n_j	L^{-3}	
Vacuum permittivity	F/m	ε_0	$M^{-1}L^{-3}T^{-4}A^2$	$8,854 \cdot 10^{-12}$
electrostatic potential	V	Φ, U	$M^1L^2I^{-1}T^{-3}$	
electric current	As	I, J	I^1	
electric current density	As/cm^2	j_j	I^1L^{-2}	
electric charge density	C/cm^3	ρ	$I^1T^1L^{-3}$	

Quantity	Unit	Symbol	Dimension	Value
electric resistance	Ω	R	$M^1 L^2 T^{-3} I^{-2}$	
electric capacity	F	C	$M^{-1} L^{-2} T^4 I^2$	
time	s	t	T^1	
plasma frequency	Hz	$\omega_{p,j}$	T^{-1}	
collisional frequency	Hz	ν_j	T^{-1}	

Table 2: Physical properties in their commonly — or for this purpose most convenient — units and corresponding SI units. If not specified, the values of each quantity refer to the afore-mentioned units.

Abstract

The Thesis Abstract is written here and usually kept to just this page. The page is kept centered vertically so it can expand into the blank space above the title too.

Physical Properties of Low Temperature RF Plasma

In this first chapter I will provide the necessary physical background for this work about the numerical simulation of low temperature capacitively coupled radio frequency plasma. Here both the mathematical basics and method for the simulation, as well as the most important aspects about the plasma properties will be explained.

1.1 Plasma Physics

1.1.1 Capacitively Coupled Radio Frequency Plasma

The experiment where after the conducted simulations is modelled after revolves around a capacitively coupled radio frequency, low temperature plasma at low pressures of oxygen. Here, I will refer to a plasma as an globally quasi-neutral gas, consisting of freely moving charges — e.g. electrons, positively and negatively ions — and neutral gas particles. The ratio between charged and neutral species defines the *degree of ionization*, which in this case is very low. The term of global neutrality emphasizes the purpose for different length scales inside the gas itself. Hence, the associated condition of neutrality by equal densities $n_e = n_i$ only is valid for areas larger than the so called *Debye sphere*. Inside this ball with a radius of λ_D the *Debye length*, the afore-mentioned neutrality is not satisfied.

The creation of a plasma is accomplished by 2 parallel metal plates, the electrodes, where on at least one an ac signal at radio frequency is applied — this kind of experimental setup is among the most common, thus being used for basic but also in-depth studies of the afore-mentioned discharges. Here, a rf signal at exactly 13,56 MHz with an amplitude between 100–1000 V will be used. This equals to a wavelength of 22,11 m for the electric field wave, which is orders of magnitude higher than the eventually simulated experiment. The use of external magnetic fields is not within the scope of this work — correspondingly, the experiment I will refer to, also did not include any kinds of magnetic confinement or manipulation.

That said, a multitude of electric setups are possible, such as coated or grounded electrodes. Therefore, different regimes of operation ensue. For example, differently driven or shaped metal plates heavily influence the charge creation process inside the plasma. In summary, the electrodes, neutral gas and electric layout resemble a dielectric hindered plate capacitor.

This simplification can be used to access important physical properties, such as an additional voltage offset on one of the electrodes or charge currents at such. A basic scheme of an asymmetric rf discharge can be seen in figure 1.1. In the case of different electrode sizes, as seen in the scheme, the potential inside the spatially restricted area between wall and discharge can change drastically. This plasma sheath forms also between grounded parts of discharge containment or probes and plasma volume. This additional direct current offset is called *self-bias* (see section 1.1.4). A dielectric displacement current between plasma sheath and volume accommodates as a result of the different time scales of particle movement (see section 1.1.5). Especially, self-bias and displacement current play a key role in the following investigations, as a capacitive coupling between electrodes and power supply is difficult to model in a numerical kinetic simulation.

A strong mathematical analysis of general plasma properties would not be suitable for this kind of work, although certain aspects will be discussed later, such as in section 1.1.4 and section 1.1.5. In comparison to other low temperature, low pressure discharges — an example could be a dielectric hindered dc discharge at high voltages, with an electrode space gap of just a couple millimeters —, radio frequency plasma are characterized by their unique transport process inside the sheath and heating mechanisms of charged species. A more in-depth discussion can be found in section 1.1.6.

1.1.2 Plasma-Wall Interaction

In the discharges bulk, neutral gas particles are excited by electron collisions and radiating visible light. However, areas around, e.g. floating metal surfaces, probes and grounded walls are darker than the bulk. This is due to the low electron density and kinetic energy in this *plasma sheath*. Though areas with vanishing electron numbers can glow because of high collision efficiencies and/or frequencies.

Electrons, in general, are of a much higher mobility μ_e and thermal velocity $v_{th,e}$. Hence they impinge onto walls and surfaces more often than other species, leading to a — in this case we consider an electronegative oxygen discharge, where the following can be assumed true — negative charge and potential.

1.1.2.1 Child-Langmuir Law

For an asymmetric ccrf discharge, dc *self bias* and displacement current are important parts of the electric system. Hence, the *Child-Langmuir Law* as a function of those properties can be written. The rf component of the excitation is neglected.

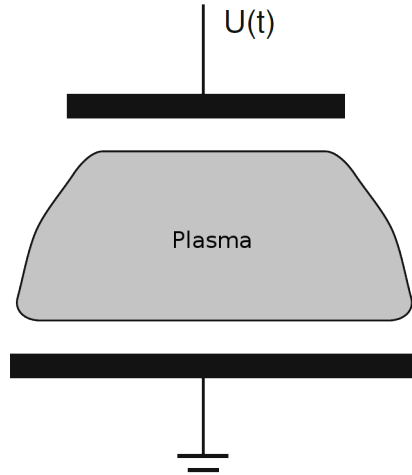


Figure 1.1: Schematic of an asymmetric discharge with one grounded and one driven electrode. The rf signal is denoted with $U(t)$. [8]

A greatly negative charged wall at $x = 0$ shall be a barrier for electrons of thermal velocity, e.g. $|\Phi(0) - \Phi(d)| \ll k_B T_e / e$. The thickness of the sheath shall be considered d . In an one-dimensional approach [8], the electron density $n_e(x)$ can be written with a *Boltzmann* distribution function $f_B(\Phi)$:

$$n_e(x) = n_e(d) \cdot f_B(\Phi) = n_e(d) \cdot \exp\left(\frac{e(\Phi(x) - \Phi(d))}{k_B T_e}\right) \quad (1.1)$$

This means that the electron density decreases exponentially towards the negatively charged wall. It can be assumed that the sheath thickness $d \ll s_{\text{mfp},i}$ the mean free path of the ions inside the plasma bulk. Hence, ions enter the sheath collisionless.

At the boundary between bulk and pre-sheath, the walls potential vanishes because of the plasmas shielding capabilities. Here, the ions are at $v_{i,0}$ speeds, therefore their density becomes:

$$n_i(x) = n_i(d) \left(1 - \frac{2e\Phi(x)}{m_i v_{i,0}^2}\right)^{-1/2} \quad (1.2)$$

Futhermore, one can assume that the kinetic energy at this point is smaller than the potential energy for the acceleration inside the pre-sheath, e.g. $m_i v_{i,0}^2 \ll |e\Phi(x)|$. Using *Poisson's* equation, and taking into account the ion-sheath interaction, equation 1.3 gives an equation for $\Phi(x)$:

$$\Delta\Phi \cong -\frac{en_i(-d)}{\varepsilon_0} \left(-\frac{2e\Phi(x)}{m_i v_{i,0}^2}\right)^{-\frac{1}{2}} \quad (1.3)$$

Solving this, and using the unpertubated ion current $j_i = n_i(d)ev_{i,0}$, one yields the result by *Langmuir*.

$$\Phi(x) = \left(\left(\frac{3}{4}(x+d)\right)^4 \left(\frac{j_i}{\varepsilon_0}\right)^2 \frac{m_i}{2e}\right)^{\frac{1}{3}} \quad (1.4)$$

Again, solving equation 1.4 for the current j_i yields the *Child-Langmuir Law* (see equation 1.5). This equation defines the ion current as a function of the unpertubated plasma bulk. In other words, the sheath changes its thickness in dependency of those certain discharge parameters, always satisfying the ion current defined by the *Child-Langmuir Law*.

$$j_i = \frac{4}{9}\varepsilon_0 \left(\frac{2e(\Phi(-d) - \Phi(0))^3}{m_i d^2}\right)^{\frac{1}{2}} \quad (1.5)$$

1.1.2.2 Surface Effects and Secondary Ion Emission

Although plasma sheath physics are influenced by bulk properties, such as temperatures and densities, the space charge area itself is mainly characterized by processes of the wall. Hence an important aspect is the absorption and re-emission of ions and electrons. Those species than have unique features, like e.g. high velocities. Let's assume the associated metal wall behind the sheath ideally absorbs all impinging, charged particles, which recombine immediately near the surface.

Secondary Electron Emission The discharges electrons are much faster and mobile than the other species, leading to the afore-mentioned negative charging and potential drop towards the wall. This accelerates the ion species up to *Bohm velocity* — see section 1.1.3 for a more in-depth discussion of the *Bohm criteria* and the ions sheath physics.

Continuity and charge conservation must be satisfied, hence the fluxes J_j of the species j must be equal at the sheath edge — into and out of the sheath:

$$J_e = J_i \quad (1.6)$$

The mentioned potential drop $\Delta\Phi$ from section 1.1.2.1, beside accelerating positive ions, reflects negative charges slower than $v \leq \sqrt{2e\Delta\Phi/m}$. Similar to equation 1.1, the electron current towards the wall can be written. Here the first moment of the electron velocity $\langle v \rangle$ is used, calculated in equation 1.8 with the electron energy distribution function (EEDF) $f_e(v)$:

$$j_e = -\frac{e}{4}n_e\langle v \rangle \exp\left(-\frac{e\Delta\Phi}{k_B T_e}\right) \quad (1.7)$$

$$\langle v \rangle = \int_{\mathbb{R}} v \cdot f_e(v) dv \quad (1.8)$$

Impinging ions are neutralized before impact by particles from the electron gas in the wall. Like before, any produced neutrals are reflected and exit the sheath collisionless — the mean free path is larger than the sheath thickness. Hence ionization is a process almost exclusively happening in the bulk or the pre-sheath.

Assuming a fast electron impacts on the wall, there is a chance of colliding with and liberating a second electron from the target. Here, the *secondary electron emission* coefficient is noted as γ : an impinging electron emits γ -many electrons from the metal. This *SEE* reduces the $\Delta\Phi$ because of an addition charge current from the wall towards the sheath edge, therefore altering the continuity condition $j_i = j_e$. A new *effective potential drop* $\Delta\Phi_{\text{eff}}$ can be written in equation 1.9. According to [] there is a critical value γ_c from which on the wall potential is unstable, leading to shifting sheath edges — the sheath edge oscillates with the rf signal anyway — and strong currents from the wall.

$$\Delta\Phi_{\text{eff}} = -\frac{k_B T_e}{e} \cdot \ln\left((1 - \gamma) \sqrt{\frac{m_i}{2\pi m_e}}\right) \quad (1.9)$$

Secondary Ion Emission Research prior to this thesis [6] indicates that ions are produced near the surface of a metal electrode and heavily accelerated in the plasma sheath. In theory, secondary emission by surface ionization — in analogy to the surface neutralization — occurs with incident atoms of thermal energy. Hence one assumes a positively biased wall at high temperatures as the target. It's valence level is therefore broadened, giving an atom A the chance to deposit an electron at the metal. After equilibrating thermally, a positive ion is emitted by chance. This statistical process can be described by a thermodynamical equation (see equation 1.11) yielding the ionization coefficient of A . In equation 1.11 a modified approach for the *Saha-Langmuir equation* on the degree of ionization in gases can be found. Here, the surface's temperature T and average work function $\bar{\Phi}_+$ are needed. Additionally, the ionization energy $I(A)$ — or impact energy —, the particle number currents of both species j and j^+ , corresponding statistical weights w , w^+ and reflection coefficients at the intrinsic potential

barrier r/r^+ are used.

$$A \rightleftharpoons A^+ + e^- \quad (1.10)$$

$$\alpha^+(A^+) = \frac{j^+}{j} = \frac{(1-r^+)w^+}{(1-r)w} \cdot \exp\left(\frac{\bar{\Phi}_+ + e\sqrt{eV_{\text{ext}}} - I(A)}{k_B T}\right) \quad (1.11)$$

At high temperatures of, e.g. 1000 K and externally applied potentials $V_{\text{ext}} < 1$ kV, the reflection associated *Schottky term* $e\sqrt{eV_{\text{ext}}}$ and the corresponding coefficients r/r^+ can be neglected — it appears to be just half of the thermal energy at room temperature. Though a theoretical approach is possible, there have't been accurate studies of such coefficients for temperatures around 300 K.

In addition to SIE of positive ions, a case for negative ions can be easily derived with small changes to equation 1.11: a negatively biased electrode is assumed and the average work function yields a different sign. The electron affinity of the incident particle B is noted as $A(B)$.

$$B + e^- \rightleftharpoons B^- \quad (1.12)$$

$$\alpha^-(B^-) = \frac{(1-r^-)w^-}{(1-r)w} \cdot \exp\left(\frac{-\bar{\Phi}_- + e\sqrt{eV_{\text{ext}}} + A(B)}{k_B T}\right) \quad (1.13)$$

Applying the former assumptions to both equations of positive and negative ions, inserting a homogeneous work function $\Phi = \bar{\Phi}_- = \bar{\Phi}_+$ for the used substrate yields the originally derived *Saha-Langmuir equations*.

$$\alpha^+(A^+) = \frac{w^+}{w} \exp\left(\frac{\Phi - I(A)}{k_B T}\right), \quad \alpha^-(B^-) = \frac{w^-}{w} \exp\left(\frac{-\Phi + A(B)}{k_B T}\right) \quad (1.14)$$

Though only considering atomic particle beams onto the wall until this point, forms similar to equation 1.14 can be derived for molecular surface interactions [5]. In case of the earlier discussed ccrf discharges, arguments like high temperatures can not be applied, hence the need for measured reflection coefficients.

Works of, e.g. [10] and [7] investigated ion beam scattering, electron loss and transport in plasma sheath environments for metal walls, especially MgO(100) surfaces. There Ustaze et al. studied incident oxygen gas particles — ions and neutrals — on magnesium oxyde surfaces. Impinging atoms became negatively charged ions, picking up electrons from the MgO of the wall. This interaction, though requiring a minimum ionization and liberation energy for the electron, is most effective at low energies < 1 eV. This is due to a maximum of residence time at the target for an incoming atom. Hence it can be considered a non-resonant charge transfer process at the anion site. For an more in-depth discussion of both electron loss and capture for anion transport processes at walls one should consider [5].

Here, due to the lack of theoretical and experimental data on ion surface production, an ion beam onto the wall will result in a anion current in opposing direction of

$$j_- = \eta j_+, \quad (1.15)$$

with a corresponding efficiency of an incident positive particle η . One should keep in mind the reaction of the plasma sheath and potential inside to an additional anion current from the wall. Also, the same stability criteria apply for η as they do for the electron emission coefficient γ . In case of SIE beyond a critical value η_c , a second plasma sheath may develop, enclosing the bulk and an inner sheath and reducing transport in-between.

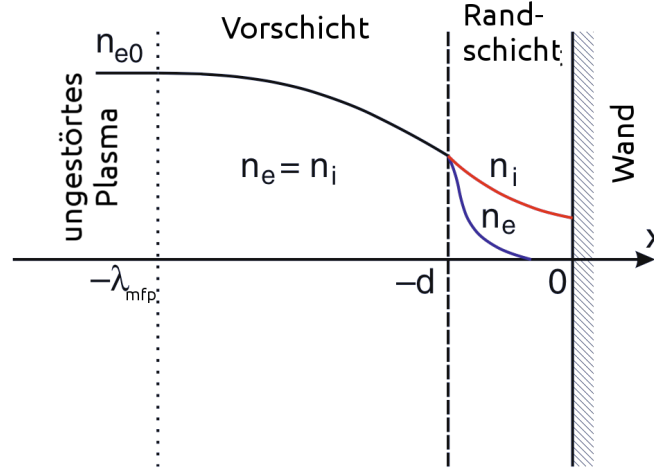


Figure 1.2: One dimensional density profiles as a function of the distance to a floating wall. Note the exponential decrease of the electron density n_e from the sheath border towards the presumably negatively charged wall. Densities already reach approximately $0,66n_{e,0}$ inside the pre-sheath. [8]

1.1.3 Bohm Criteria

In section 1.1.2 the behaviour of charge particle densities inside the plasma sheath has been discussed. In contrast to the discharge volume, those densities do not satisfy the quasi-neutrality condition in a distance of d from the wall anymore. Though we know that the sheath is a spacially restricted area around electrostatic floating surfaces, a physical law concerning this circumstance has not been derived here. So the question ensues, why the area of electron depletion does not extend further into the discharge volume.

To answer this question, one has to take a look at a substitutional system. This will be a, likewise mechanical, one-body extremal problem of a point mass. In this case only kinematic potentials with inverted parabolic maxima are of interest. Therefore, in this unstable equilibrium, a small perturbation culminates into a large force on the test body.

To see the quality of this example, one has to take a look at the second order differential equation of the afore-mentioned mechanical problem and the electrostatic *Poisson's equation* (see equation 1.16).

$$m \frac{d^2 \vec{r}}{dt^2} = -\frac{dV}{d\vec{r}} \quad \Leftrightarrow \quad \Delta_{\vec{r}} \Phi = -\frac{d\Psi}{d\Phi} = f(\Phi) \stackrel{\text{Poisson's}}{=} \frac{\rho}{\varepsilon_0} \quad (1.16)$$

For an instability, the force on the test body must increase with the distance from the equilibrium, hence the equation 1.18 is used to calculate the exact velocity at which an ion is entering the sheath. This results in the first *Bohm criteria*.

$$0 > \left. \frac{d^2 \Psi}{d\Phi^2} \right|_{\Phi=0} \stackrel{\text{equation 1.16}}{=} \left. \frac{d}{d\Phi} \left(\frac{n_e(x) - n_i(x)}{\varepsilon_0} \right) \right|_{\Phi=0} = \frac{en_e(-d)}{\varepsilon_0} \left(\frac{e}{k_b T_e} - \frac{e}{m_i v_{i,0}^2} \right) \quad (1.17)$$

$$\Rightarrow v_{i,0} \geq v_{i,B} = \sqrt{\frac{k_B T_e}{m_i}} \quad (1.18)$$

Analogously you can define the so called *Mach number* $M = v_{i,0}/v_{i,B}$, where $v_{i,B}$ denotes the *Bohm velocity*.

Now, to understand why the sheath does not extend further than a fixed distance d from the discharge boundary, the particle movement has to be investigated on a smaller scale. As seen above, there is an electric field in the *pre-sheath* that accelerates the ions to $v_{i,B}$. In addition, quasi-neutrality is still satisfied here:

$$n_i(x) = n_{i,0} \exp\left(\frac{e\Phi(x)}{k_B T_e}\right) = n_e(x) . \quad (1.19)$$

Still, $\Phi(x)$ is the potential inside the pre-sheath from section 1.1.2 and $n_{i,0}$ the unpertubated density from the plasma *bulk*. A greater part of the ion transport process in this area is governed by collisions with neutral gas particles, hence the velocity distribution function with the collision frequency $\nu_{n,i}$ has to be rewritten:

$$\frac{dv_i}{dx} = \frac{\nu_{n,i} v_i^2}{v_B^2 - v_i^2} . \quad (1.20)$$

From the singularity in equation 1.20 at $v_i = v_B$ and the knowledge of $\Phi(x)$ at the wall, one can calculate the sheath thickness d . Furthermore, ions with velocities smaller than the Bohm velocity are being accelerated inside the pre sheath. According to equation 1.18 velocities greater than v_B are not allowed here. This is, together with equation 1.20 the reason why the ion velocity is exactly v_B at the boundary of the plasma sheath and thus a positive space-charge ensues.

$$M \geq 1 \Leftrightarrow v_i(-d) \geq v_B \quad (1.21)$$

Conclusively, at the sheath boundary equation 1.21 is satisfied.

At $x = -d$, both negative and positive charge density decreased to $n_i = n_e \approx 0,66n_{e,0}$ (see figure 1.2), where the potential is approximately $-k_B T_e/2e$ because of the currents onto the wall. In summerization, the plasma does not ‘see’ its sheath, because the ion dynamic discussed before is spatially restricted. The sheath only develops where there is electron depletion or an externally applied, negative potential.

1.1.4 Self Bias Voltage

An important step towards the electric characterization of such ccrf discharges is the development of a replacement circuit, see figure 1.3a. Thus, one can define a specific impedance for a rf discharge of excitation frequency ω . The value of ε_p resembles the permeability of the working gas between the driven and/or grounded electrode [8]. In addition, this volume has the capacity C_p — the capacity of a cubicle with a cross section A , thickness b and electron-neutral collision frequency $\nu_{e,n}$ calculates like equation 1.22.

$$\varepsilon_p = 1 - \frac{\omega_{p,e}^2}{\omega(\omega - \mathbf{i}\nu_{e,n})}, \quad C_p = \varepsilon_p C_0 = \varepsilon_p \varepsilon_0 \frac{A}{b} \quad (1.22)$$

$$Z_p = \left(\mathbf{i}\omega C_p + \frac{1}{\frac{\omega_{p,e}^2}{\omega_{p,e}^2 C_0} (\nu_{e,n} + \mathbf{i}\omega)} \right)^{-1} \quad (1.23)$$

The equation 1.23 represents the full electrical impedance, consisting of the inverse sum of real and imaginary resistance, as well as the capacity of the neutral gas volume. Here, $\mathbf{i}\omega/(\omega_{p,e}^2 C_0)$ characterizes the electrons inertia in regard to an external excitation ω . The real

part $\nu_{e,n}/(\omega_{p,e}^2 C_0)$ denotes the resistance by neutral particle collisions.

For high excitation frequencies, e.g. 13,56 MHz the bulk impedance can be neglected (see equation 1.23, [4]). Both sheath capacities of anode and cathode take the dominant part. Therefore, the discharge potential and voltage can be written as:

$$U(t) = U_{sb} + U_{rf} \sin(\omega t), \quad \Phi_p(t) = \overline{\Phi_p} + \Phi_{rf} \sin(\omega t) \quad (1.24)$$

Both electrodes sheath collapses completely during a full cycle of $U_{rf}(t)$, which is why charges can impinge onto the surface and force the plasma potential Φ_p to equal out locally with the walls. A short circuit between plasma and sheath occurs when Φ_p becomes negative with regard to the excitation. The equation 1.25 and figure 1.3b express this circumstance.

$$\Phi_p \text{ max} = \overline{\Phi_p} + \Phi_{rf} \geq U_{sb} + U_{rf}, \quad \Phi_p \text{ min} = \overline{\Phi_p} - \Phi_{rf} \geq 0. \quad (1.25)$$

If there is no special coupling between electrode and electrical driver, the equality in equation 1.25 is true. However, if a capacitive coupling is used, there can't be any net current between excitation and electrode. The capacitance can not be inverted over the course of one rf cycle. The electron currents are then equal on both electrodes, therefore shifting the minimum plasma potential to ground and the maximum to the excitation.

Finally, the dc *self bias* part U_{sb} and the mean plasma potential $\overline{\Phi_p}$ are

$$\overline{\Phi_p} = \frac{1}{2} (U_{sb} + U_{rf}), \quad U_{sb} = \frac{C_1 - C_2}{C_1 + C_2} U_{rf}. \quad (1.26)$$

If the excitation frequency ω is small compared to other time scales, e.g. electron and ion plasma frequencies, the electron current from the sheath j_L becomes bigger than the displacement current j_{dc} . Hence the electron current onto the driven electrode decreases by a maxwellian factor — this is a function of the thereon applied voltage — compared to the corresponding ion current. Conclusively, the electrodes sheath impedance is bigger than those of the floating walls. Together with equation 1.24 and equation 1.18 the plasma potential Φ_p approximately vanishes,

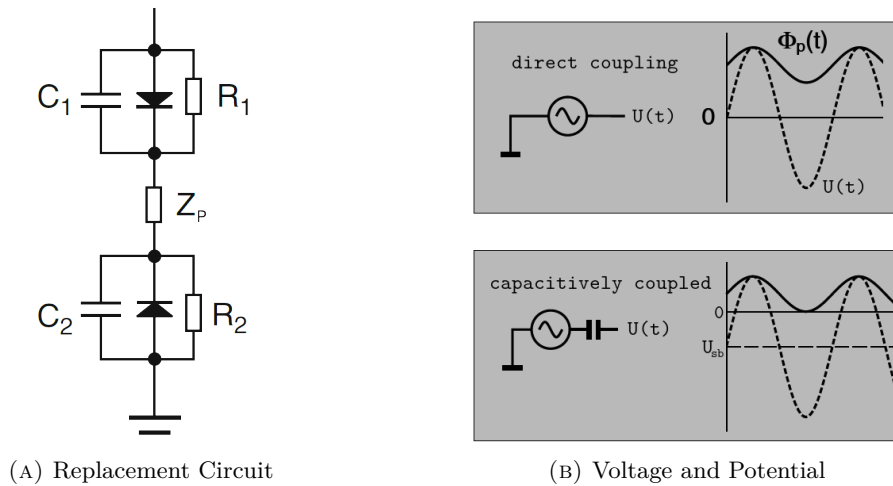


Figure 1.3: Figure for an asymmetrically driven ccrf discharge. [8]

(A): Z_p denotes the impedance of the plasma bulk. A diode represents the directed electron current from the sheath into the discharge volume. R_j and C_j are the electrical properties of the positive space-charge area.

(B): Schematic of potential and voltage of a direct capacitively coupled rf discharge.

requiring only the currents onto the driven electrode to equal out. For small values of ω equation 1.27 yields the *self bias voltage* [8]. Here, \mathbf{J}_0 denotes the zeroth order *Bessel function*.

$$U_{sb} = \frac{k_B T_e}{e} \ln \left[\mathbf{J}_0 \left(\frac{e U_{rf}}{k_B T_e} \right) \right] \quad (1.27)$$

In (insert fig:imagandreal here) the voltage's real and imaginary part are shown for an exemplary ccrf discharge. One can examine there that the self bias never disappears for excitations $U_{rf} \neq 0$, hence becoming an important part for capacitively coupled plasma.

1.1.5 Dielectric Displacement Current

Due to their higher mobility and plasma frequency $\omega_{p,e}$, the electron distribution can follow an external excitation with a similarly high frequency much better than the heavier ions species. Because of that, one will assume those as nearly stationary, e.g. $\omega_{p,i} \ll \omega_{p,e}, \omega_{rf}$. Investigating the circumstances and consequences of this relation yields the displacement current j_d .

Lets suppose there is an area of thickness d in front of a negatively charged wall, where the electron density is negligible and the corresponding ion property constant at $n_{0,i}$. Thus an electric field of

$$E_0 = -en_{0,i}d/\varepsilon_0 \quad (1.28)$$

establishes. If the wall potential now decreases due to electron bombardement or external manipulation, the sheaths border moves further inside into the discharges volume with the velocity $v = ds_1/dt$. Thus, the sheath expansion and hence charge movement creates an additional *displacement current* j_d , which is compensated with $j_{d,e}$ the electron current from this border displacement. Hence charge conservation and continuity is satisfied [1].

$$j_d = -en_{0,i}v = -j_{d,e} \quad (1.29)$$

Electrons that are pushed out of this positive space-charge area then contribute to the plasma bulk density, and conclusively, to the quasi neutrality $n_e = n_{0,i}$. But in case of a harmonically driven discharge, the sheath in front of the opposing electrode is shrinking with $ds_1 = -ds_2$. Hence, the bulks spatial expansion and position are oscillating sinusoidal, or: the sheaths thickness oscillates harmonically around a mean value, e.g. s_0 . The associated voltage drop across the discharge [8] between the sheath potentials $U_{1/2}$ would be

$$\Delta U = U_1 - U_2 = -\frac{2en_{i,0}s_0}{\varepsilon_0} \exp(i\omega t) \quad (1.30)$$

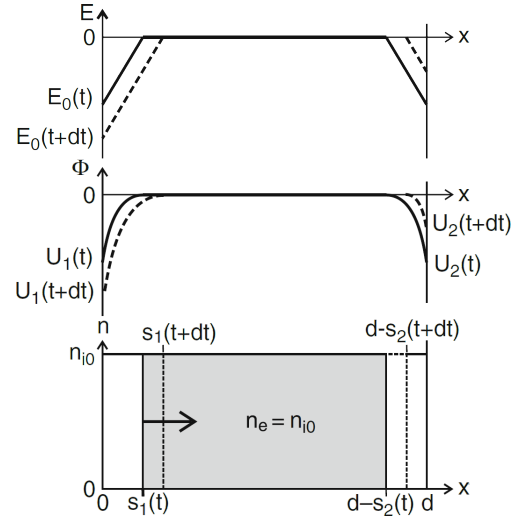


Figure 1.4: One dimensional density, potential and electric field for an asymmetric, harmonically driven discharge. Note the moving sheaths border. [8]

1.1.6 Heating Mechanisms

Low-pressure capacitive rf plasma can be stabilized mainly by collisionless heating in the sinusoidal rf modulated discharge sheaths, like it was proposed earlier in section 1.1.2.1 and the following. Most theoretical models assume a ‘hard wall’ approximation (HWA), where the electron are considered to collide elastically with the oscillating sheath edge. Heating power is then averaged by reverse and forward energy fluxes into and out of the sheath respectively. Thus giving an easy access to heating mechanisms of the proposed discharges, this model is very sensitive to *ab initio* information about EEDF, sheath transit times and particle losses. [3].

The heating mechanism in such low pressure plasma is of particular importance, because collisions are rare and sheath processes are key to the sustainability of the discharge (see e.g section 1.1.3). The afore-mentioned HWA uses the ‘*Fermi acceleration*’ argument, which implies that the particles are heated or cooled due to the sheaths sinusoidal oscillation and a corresponding de-/acceleration. This process, though relying on enough randomization in phase-space inside the bulk, sufficiently creates a net heating of the plasma [3, 2]. This is referred to as *stochastical heating*.

Here one will consider the sheaths electric field as constant, $E = U_{sb}/s_0$, the bulks expansion l and the sheaths thickness being modulated cosinusoidal. The equation of motion for an electron in the sheath is written below.

$$d(t) \approx s_0 \left(1 + \frac{U_{rf}}{U_{sb}} \cos(\omega t) \right) \quad (1.31)$$

$$m_e \frac{d^2 x}{dt^2} = -\frac{eU_{sb}}{s_0} \quad (1.32)$$

The latter equation is introduced as dimensionless with the corresponding parameters: $\alpha = m_e \omega^2 s_0^2 / eU_{sb}$, $\beta = U_{rf}/U_{sb}$ and $\epsilon = s_0/l$. Integrating yields the velocity of an electron as it moves through the sheath $\mu(\tau)$.

The transit time τ is considered for one pass through the sheath of the particle. It can be used to calculate the change in velocity experienced by the electron on each bounce between this oscillating and a fixed wall — this would be the lowest order *fermi acceleration*. Let there be two distinct points in motion, where the particle enters (index n) and re-enters (index $n+1$) the sheath. This gives, using φ_n the phase of the sheath, for the transit time and, finally, the velocity [2]

$$\tau_n \approx \frac{2\alpha(\mu_n - \beta \cos \varphi_n)}{1 + \alpha\beta \cos \varphi_n}, \quad \mu_{n+1} = -\mu + \frac{2(\mu_n - \beta \sin \varphi_n)}{1 + \alpha\beta \cos \varphi_n} \quad (1.33)$$

There are different approaches on the heating in low-pressure, low-temperature rf plasma.

1.2 Negative Ion Physics

1.2.1 Anion Production

1.2.2 Dynamics and Collisions

1.3 Particle-in-Cell Simulations with Monte Carlo-Collisions

1.3.1 Principles

1.3.2 2d3v PIC

1.3.3 Monte Carlo-Collisions

Validation of Simulation by 1d comparison

2.1 Axial density profiles

2.2 Velocity and energy distributions

2.3 Transition to 2d simulation

Simulation of capacitively coupled rf discharges

3.1 Experimental setup

Giving the necessary background in section 1.1.2.2 and providing the crucially important comparison of the previous chapter 2, the afore-mentioned effects of highly energetic negative oxygen ions can now be further investigated.

3.1.1 Reference Discharge

Here, the referenced experiment was used by Küllig et al. [6] and Scheuer [9], and consists of a cylindrical setup, filled with oxygen at low pressures and gas flow rates (see figure 3.1). The stainless steel vacuum chamber had a diameter and height of 40 cm respectively and was filled with the process gas oxygen (O_2) at 5 sccm (**FC**). The discharge configuration consisted of an electrode in the center with 10 cm of diameter and a rf generator, constantly operating at a frequency of 13,56 MHz and power outputs between 5 and 150 W (**RF** and **AN**), leading to applied voltages in the range of 100–1500 V. Shielding and discharge enclosure/chamber walls were grounded, therefore yielding a large area ratio between driven and grounded electrode and

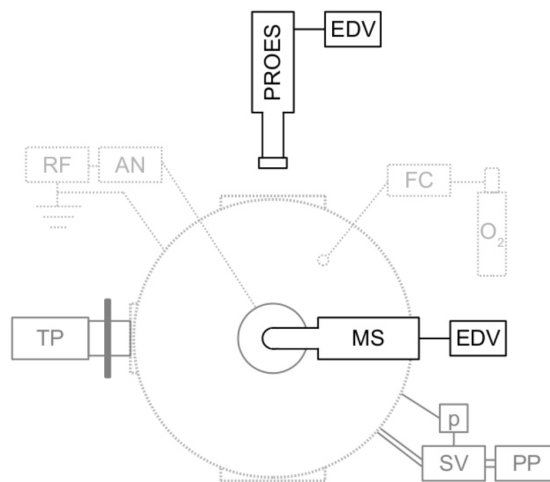


Figure 3.1: Top-down view schematic of the experiment [9], [6]. Shown is the setup without microwave interferometer, like it was used by Küllig et al.

establishing a heavily asymmetric plasma. In addition, the powered electrode was coupled capacitively with the external generator, emphasizing the effect of the, in section 1.1.4 introduced self bias voltage. The value of U_{sb} ranged, depending on power output and discharge pressure, from -100 up to 500 V. In [6] the experiment was pulsed with short discharges at a frequency of 10 Hz. Line integrated measurements resulted in an average electron density of around 10^{11} – 10^{12} cm^{-3} . Showing a schematic top-down view of the experiment is figure 3.1. Here, the large ratio between driven and grounded parts is very well visualized. Hence, in later simulations it will be of sufficient accuracy to restrain the virtualized volume to a smaller setup.

The figure below includes further diagnostics like a mass spectrometer (**MS**) and phase resolved optical emission spectroscopy (**PROES**). The latter measured the mentioned densities via line integration across the plasma volume. The MS is a key instrument for the investigation pursued in this thesis, as it also measures species counts with respect to their contribution to their corresponding energy distribution function. For example, the ions created via secondary processes in the discharge sheath are accelerated towards the bulk and thus get into the MS with their characteristic speeds and mass. A significant increase of electron density was found for rf powers larger than 50 W or -220 V self bias voltage [6]. This led to a correlating negative oxygen ion density reduction and decrease of the electronegativity ratio $\bar{n}_{i,-}/\bar{n}_e$ from 4 to $0,03$. During a different operation mode — called α -mode, contrary to the afore-mentioned γ -mode — at less than 50 V output power, electronegativity rises again, as well as the electron temperature T_e , yielding higher rate coefficients for, e.g. dissociative electron attachment and the alike. See section 1.2.1 for a more detailed approach.

3.1.2 Simulated Discharge

All of the above conditions are sufficient for a practical approach at a laboratory ccrf discharge with great repeatability. Though being highly optimized and developed over the course of many years, the twodimensional particle-in-cell code outlined above does not provide the tools and performance to feasibly simulate such large areas and particle numbers. Hence, one will reside to reducing the numerical expense by virtualizing smaller discharge areas and average densities, while trying to satisfy the same physical processes exhibited in [6].

The afore-mentioned 2d3v PIC code is used to simulated the referenced experiment. The spatial dimensions will be the radial component r and axial coordinate z . The geometry and simulation is optimized for cylindrically symmetric gas discharges.

To represent the strong asymmetry between driven and grounded wall areas, the sizes of anode, cathode and grounded chamber parts have been choosing accordingly. The experimental values for the self bias voltage U_{sb} were used to create a dc offset on-top of the rf voltage U_{rf} at the cathode. The domain composition with cells of width $\lambda_{D,e}/2$ (see section 1.3.1) makes it even more difficult to appropriately model the system. Hence a smaller discharge volume of a $4,5$ cm radius and an electrode gap of $2,5$ cm will be simulated. This usually leads to cell counts up to $2 \cdot 10^5$, which is small in comparison to the ‘real’ experiment, which would have to be covered by over 10^6 cells. Furthermore, the numerical expense grows with $N \log(N)$, and N being the particle number inside the cells (see section 1.3).

One has chosen pressures between 2 Pa and 10 Pa, with the possibility of changing it later during the discharges simulation — e.g to change the bulk volume and densities. The secondary ion emission efficiency was set to $\eta = 0,03$ in all cases, yielding a stable plasma sheath and hence SIE current into the bulk. In addition, a constant self bias of -200 V was applied at the

cathode. The radio frequency was set to 13,56 MHz.

The governing electron density and temperature were set to $5 \cdot 10^9 \text{ cm}^{-3}$ and 5 eV respectively, which, as an initial value and property for scale, is sufficient for the necessary rate coefficients mentioned above. This led to the following important scales of simulation:

$$\lambda_D = 0,0235 \text{ cm}, \quad \omega_{p,e} = 3,99 \cdot 10^9 \text{ Hz} \quad (3.1)$$

$$\Rightarrow \Delta x = \frac{1}{2} \lambda_D = 0,01174 \text{ cm}, \quad \Delta t = 0,2 \cdot \omega_{p,e} = 5,015 \cdot 10^{-11} \text{ s} \quad (3.2)$$

Thus a single rf cycle at the given frequency takes 1470 steps, and the domain measures 384 and 213 in radial and axial dimension respectively. An ion temperature is adjusted via the fraction $T_i/T_e = 0,008$, hence the corresponding velocities for the previously defined electron temperature $T_e = 5 \text{ eV} = 5,8 \cdot 10^4 \text{ K}$ are found to be

$$v_{th,e} = 9,37 \cdot 10^5 \frac{\text{m}}{\text{s}}, \quad c_{s,e} = 3,87 \cdot 10^3 \frac{\text{m}}{\text{s}} \quad (3.3)$$

$$v_{th,i} = 558,38 \frac{\text{m}}{\text{s}}, \quad c_{s,i} = 371,44 \frac{\text{m}}{\text{s}} \quad (3.4)$$

Here, a single millisecond of operation takes days, if not weeks to simulate with a given timestep, like in equation 3.2. Due to this and the fact, that the unit cell volume increases with the layer index of the radial coordinate — one has to keep in mind that the cylindrical geometry is key to the simulation because important simplifications and assumptions inside the code itself are made upon that premise —, each particle carries an additional statistical weight. For example, a virtual neutral gas molecule of O_2 may represents up to 10^8 ‘real’ particles in a laboratory plasma. This saves a vast amount of computational time by immensely reducing the particle counts necessary to sufficiently model the investigated physical processes. In this case, a single neutral gas particle is statistically amplified by a factor of $\approx 9,3 \cdot 10^7$ to account for the gas density at 5 Pa and $\approx 300 \text{ K}$. This number is crucial to all collisional processes, where the molecular species O_2 is involved. Charged particle species share a common number amplification of 8489. On top of both super particle factors, a scaling $\sim 1/r$ is applied to consider the variable cell volume.

Another numerical tool is a constant neutral gas background. In the afore-mentioned experiment, a working gas reservoir and flow rate meter control the pressure and exchange of O_2 inside the chamber. Due to the slow transition velocities of the cold neutral species, a working gas current from e.g. behind an electrode is not feasible in this simulation. Collision rates and reaction coefficients are destroying neutral gas particles faster than they can be sufficiently supplied to the discharge. Hence, the O_2 molecules are initiated at time $t = 0$ of the simulation — this is done with respect to pressure, super particle factor and the alike —, and are afterwards not altered in number or location. Though collision routines are still exercised, the corresponding push of the neutral species is skipped.

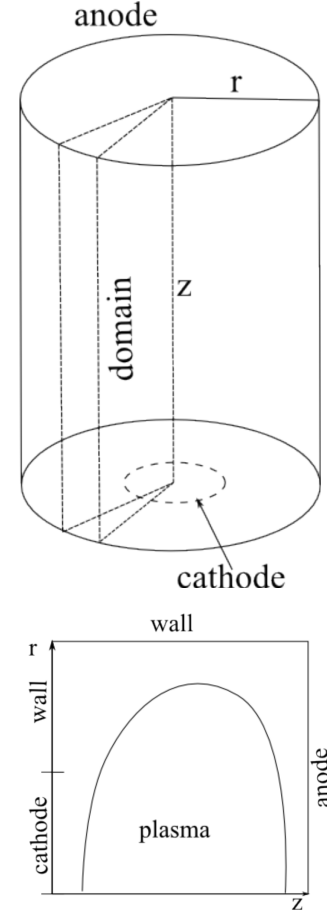


Figure 3.2: Simplified cylinder schematic for the simulated experiment. The slice depicted in the top is shown below. There, boundaries and bulk position are outlined.

3.2 Simulated ccrf Oxygen Discharge

In the collection of ?? twodimensional densities and potential are shown. Again, parameters were chosen as $U_{\text{rf}} = 400 \text{ V}$, $p = 5 \text{ Pa}$ and the initial species attributes to be $T_e = 5 \text{ eV}$, $n_{e,0} = 5 \cdot 10^9 \text{ cm}^{-3}$ and $T_i/T_e = 0,008$ respectively.

3.3 Anion Energy Distributions in Oxygen

Conclusion

Appendix

quantity	equation	relevance
Debye length	$\lambda_{D,j}^2 = \frac{\varepsilon_0 k_B T_j}{n_j e^2}$ $\lambda_D^2 = \left(\lambda_{D,e}^{-2} + \lambda_{D,i}^{-2} \right)^{-1}$	distance around a charge, at which quasi-neutrality is satisfied, λ_D is the combined screening length from individual species
plasma parameter	$N_D = n \frac{4}{3} \pi \lambda_D^3$	number of particles inside Debye sphere, if $N_D \gg 1$ an ionized gas is considered a plasma (degree of ionization)
plasma frequency	$\omega_{p,j}^2 = \frac{n_j e^2}{\varepsilon_0 m_j} = \frac{v_{th,j}}{\lambda_{D,j}} = \frac{1}{\tau_j}$	upper limit for interaction with fields/forces or external excitations inverse screening time
thermal velocity	$v_{th,j}^2 = \frac{k_B T_j}{m_j}$	mean velocity from kinetic theory of gases
coulomb logarithm	$\ln(\Lambda)$ $\Lambda = \frac{b_{\max}}{b_{\min}} = \lambda_D \cdot \frac{4\pi\varepsilon_0\mu v_{th}^2}{e^2}$	dimensionless scale for transport processes inside discharge fraction of probability for a cumulative 90° scattering by many small perturbation collisions and a single right angle scattering
collision frequency	$\nu_j = \frac{e^4 n_j \ln(\Lambda)}{8\sqrt{2} m_j \pi \varepsilon_0 (k_B T_j)^{3/2}}$	two body coulomb collision frequency inside species j
particle distance & mean free path	$\bar{b} = \frac{\hbar}{m_j v_{th,j}}$ $s_{mfp,j} = \frac{v_{th,j}}{\nu_{j,k}}$	mean inter particle distance for species j free flight between subsequent collisions of species j and k with collision frequency $\nu_{j,k}$

quantity	equation	relevance
speed of sound	$c_S^2 = \frac{\gamma Z k_B T_e}{m_i}$ $\gamma = 1 + 2/f = 5/3$	speed of longitudinal ion waves at electron pressure adiabatic coefficient with f, the kinetic degree of freedom
Debye-Hückel potential	$\Phi = \frac{Q}{4\pi\epsilon \vec{r} } e^{-\frac{ \vec{r} }{\lambda_D}}$	electrostatic potential of charge particle Q at distance $ \vec{r} $, equal to coulomb interaction with additional shielding by charged particles
drift velocity	$v_{d,j} = u_j = \frac{j_j}{n_j q} = \frac{m\sigma E}{\rho e f}$	average velocity of a particle in a conductor with an electric field applied E , where N is the number of free electrons per atom
electric mobility	$\mu_j = \frac{v_d}{E}$	ability of charged particle of moving through an electric field — with presence of a con- ductor

Table A.1: Selection of physical properties of a low temperature ccrf discharge. The index j denotes the species, e.g. electrons, ions. Used quantities can be found in the preface in table 2.

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